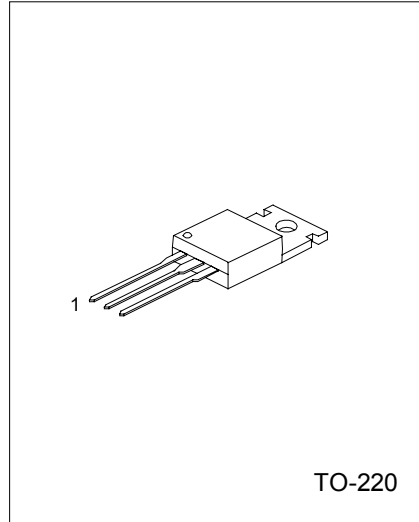
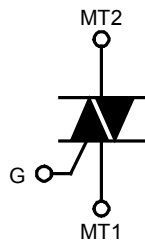


TRIACS

DESCRIPTION

Glass passivated , sensitive gate triacs in a plastic envelope, intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants.

SYMBOL



1:MT1 2:MT2 3:GATE

ABSOLUTE MAXIMUM RATINGS (T_j=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Repetitive Peak Off State Voltage	V _{DRM}	500*	V
UT138E-5		600*	
UT138E-6		800	
UT138E-8			
RMS On-state Current (Full sine wave, T _{mb} ≤99°C)	I _{T(RMS)}	12	A
Non-repetitive Peak. On-State Current (Full sine wave, T _j =25°C prior to surge)	I _{TSM}	95	A
t=20ms		105	
t=16.7ms			
I ² t For Fusing (t=10ms)	I ² t	45	A ² s
Repetitive Rate of Rise of On-state Current after Triggering (I _{TM} =20A, I _G =0.2A, dI _G /dt=0.2A/μs)	dI _T /dt	50	A/μs
T2+ G+		50	
T2+ G-		50	
T2- G-		10	
T2- G+			
Peak Gate Voltage	V _{GM}	5	V
Peak Gate Current	I _{GM}	2	A
Peak Gate Power	P _{GM}	5	W
Average Gate Power (Over any 20ms period)	P _{G(AV)}	0.5	W
Operating Junction Temperature	T _j	125	°C
Storage Temperature	T _{stg}	-40~150	°C

*Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15A/μs.

THERMAL RESISTANCES

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Thermal Resistance, Junction to Mounting Base Full cycle Half cycle	Rthj-mb			1.5 2.0	K/W
Thermal Resistance, Junction to Ambient In free air	Rthj-a		60		K/W

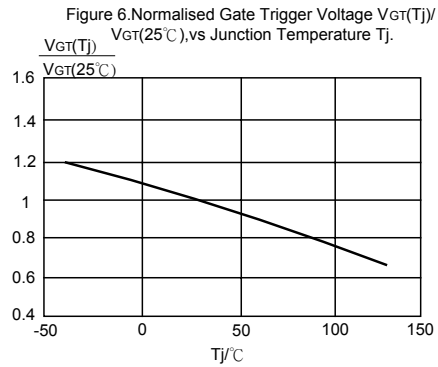
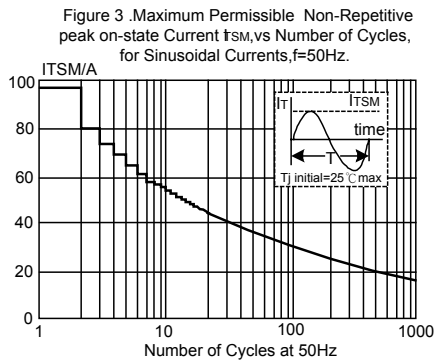
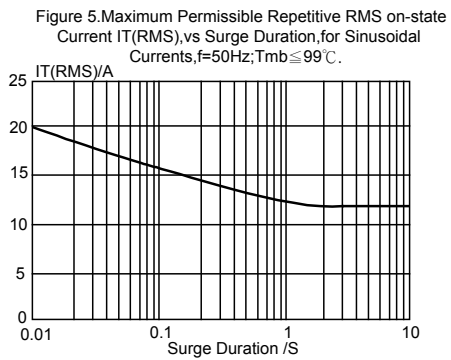
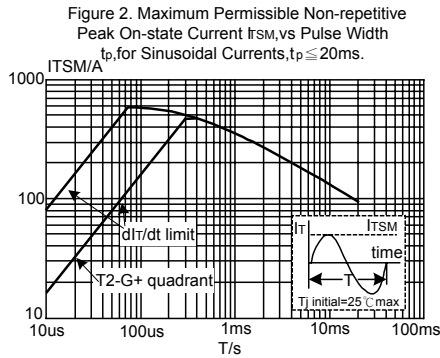
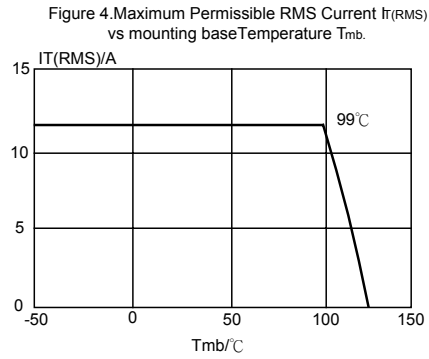
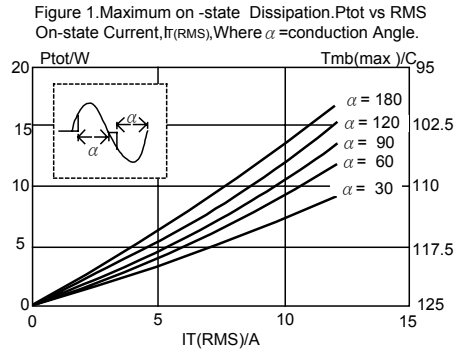
STATIC CHARACTERISTICS (T_j=25°C, unless otherwise specified)

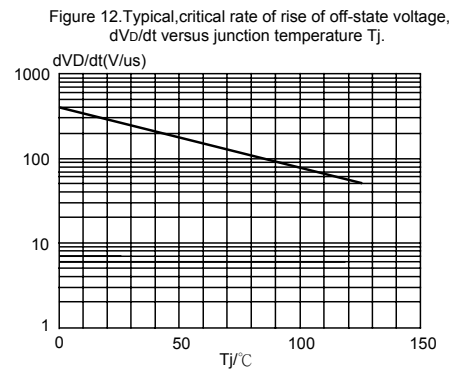
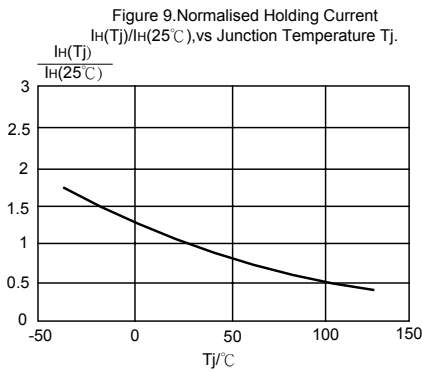
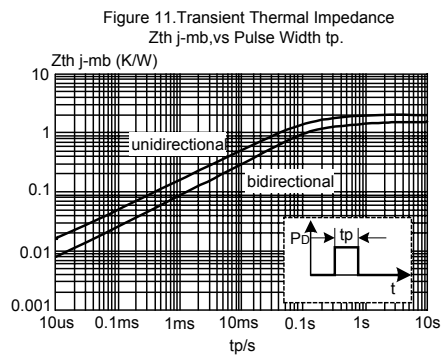
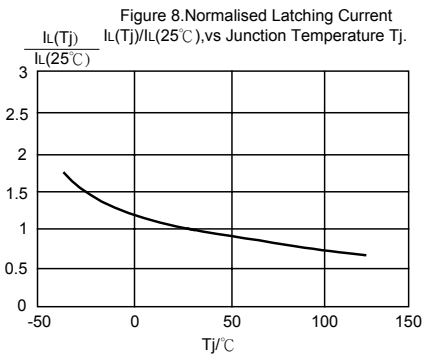
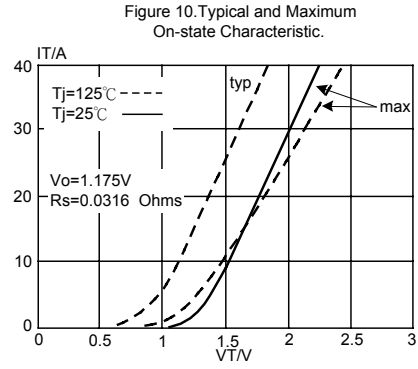
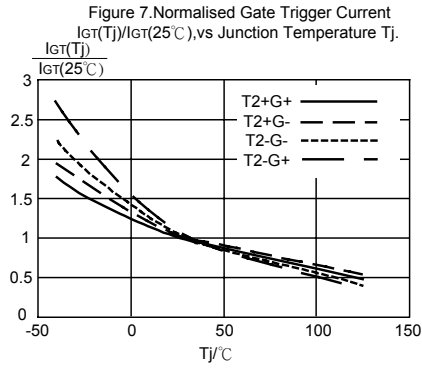
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate Trigger Current	I _{GT}	V _D =12V, I _T =0.1A T2+ G+ T2+ G- T2- G- T2- G+		2.5 4.0 5.0 11	10 10 10 25	mA
Latching Current	I _L	V _D =12V, I _{GT} =0.1A T2+ G+ T2+ G- T2- G- T2- G+		3.2 16 4.0 5.5	30 40 30 40	mA
Holding Current	I _H	V _D =12V, I _{GT} =0.1A		4.0	30	mA
On-State Voltage	V _T	I _T =15A		1.4	1.65	V
Gate Trigger Voltage	V _{GT}	V _D =12V, I _T =0.1A V _D =400V, I _T =0.1A, T _j =125°C		0.7 0.25	1.5	V V
Off-state Leakage Current	I _D	V _D =V _{DRM(max)} , T _j =125°C		0.1	0.5	mA

DYNAMIC CHARACTERISTICS (T_j=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Critical Rate Of Rise Of Off-State Voltage	dV _D /dt	V _{DM} =67% V _{DRM(max)} , T _j =125°C Exponential waveform, Gate open circuit		50		V/μs
Gate Controlled Turn-on Time	t _{gt}	I _{TM} =16A, V _D =V _{DRM(max)} , I _G =0.1A dI _G /dt=5A/μs		2		μs

TYPICAL CHARACTERISTICS





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